

## R-C Thermal Model Parameters

### DESCRIPTION

The parametric values in the R-C thermal model have been derived using curve-fitting techniques. These techniques are described in "[A Simple Method of Generating Thermal Models for a Power MOSFET](#)"[1]. When implemented in P-Spice, these values have matching characteristic curves to the Single Pulse Transient Thermal Impedance curves for the MOSFET.

R-C values for the electrical circuit in the Foster/Tank and Cauer/Filter configurations are included.

*Note:*

*For a detailed explanation of implementing these values in P-SPICE, refer to [Application Note AN609 Thermal Simulations Of Power MOSFETs on P-SPICE Platform](#).*

### R-C THERMAL MODEL FOR TANK CONFIGURATION



<b>R-C VALUES FOR TANK CONFIGURATION</b>			
Thermal Resistance (°C/W)			
Junction to	Ambient	Case	Foot
RT1	188.2538	N/A	98.6067
RT2	32.8812	N/A	193.1619
RT3	109.7194	N/A	102.1149
RT4	394.1456	N/A	176.1165
Thermal Capacitance (Joules/°C)			
Junction to	Ambient	Case	Foot
CT1	543.0109 u	N/A	4.3742 m
CT2	86.5338 u	N/A	741.8607 u
CT3	424.7724 m	N/A	12.8222 m
CT4	2.7530 m	N/A	141.5704 u

*This document is intended as a SPICE modeling guideline and does not constitute a commercial product data sheet. Designers should refer to the appropriate data sheet of the same number for guaranteed specification limits.*

**R-C THERMAL MODEL FOR FILTER CONFIGURATION****R-C VALUES FOR FILTER CONFIGURATION**

Thermal Resistance ( $^{\circ}\text{C}/\text{W}$ )			
Junction to	Ambient	Case	Foot
RF1	66.8268	N/A	187.0703
RF2	248.3816	N/A	188.5591
RF3	300.9595	N/A	162.0852
RF4	108.8321	N/A	32.2854
Thermal Capacitance (Joules/ $^{\circ}\text{C}$ )			
Junction to	Ambient	Case	Foot
CF1	124.9472 u	N/A	102.9461 u
CF2	418.7308 u	N/A	253.7893 u
CF3	2.6668 m	N/A	2.3003 m
CF4	349.5837 m	N/A	51.7627 m

Note: NA indicates not applicable

Reference:

[1] "A Simple Method of Generating Thermal Models for a Power MOSFET" by Wharton McDaniel and Kandarp Pandya, IEEE / SEMITHERM 2002

